





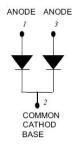
# 209CNQ135/209CNQ150 SCHOTTKY RECTIFIER



#### **Features**

- 175℃ T<sub>J</sub> operation
- Center tap module
- High purity, high temperature epoxy encapsulation for
- enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Base plate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Circuit Diagram**



### **Applications**

- High current switching power supply
- Plating power supply
- Free-Wheeling diodes
- Reverse battery protection
- Converters
- UPS System
- Welding

## Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V <sub>RRM</sub>	-	135	209CNQ135	\/
DC Blocking Voltage	$egin{array}{c} V_{RWM} \ V_{R} \end{array}$		150	209CNQ150	V
Average Rectified Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =110°C,		100(Per Leg)	Α
Average receiled Forward Current	IF(AV)	rectangular wave form	200(Per Device)		, ,
Peak One Cycle Non-Repetitive Surge Current (Per Leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	1440		Α

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •









## **Electrical Characteristics:**

Characteristics	Symbol	Symbol Condition		Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 100A, Pulse, T <sub>J</sub> = 25 °C @ 200A, Pulse, T <sub>J</sub> = 25 °C	0.84 0.93	1.03 1.22	V
	V <sub>F2</sub>	@ 100A, Pulse, T <sub>J</sub> = 125 °C @ 200A, Pulse, T <sub>J</sub> = 125 °C	0.72 0.79	0.76 0.82	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_{R,} T_J = 25  ^{\circ}\text{C}$	0.04	3	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_{R,} T_J = 125  ^{\circ}\text{C}$	2.26	45	mA
Junction Capacitance(Per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	1993	3000	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

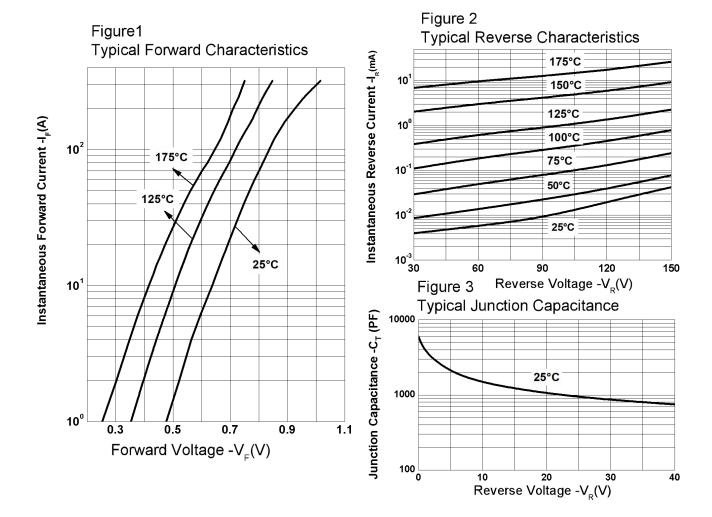
Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	ΤJ	-	-55 to +175		°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175		°C
Typical Thermal Resistance Junction to Case(Per leg)	R <sub>θJC</sub>	DC operation	0.40		°C/W
Typical Thermal Resistance Junction to Case(Per package)	R <sub>θ</sub> JC	DC operation	0.20		°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.08		°C/W
Mounting Torque	T <sub>M</sub>	-	Mounting Torque Terminal	24(min) 35(max) 35(min)	Kg-cm
			Torque	46(max)	
Approximate Weight	wt	-	91 g		
Case Style	PRM4 Non-Isolated				







## **Ratings and Characteristics Curves**

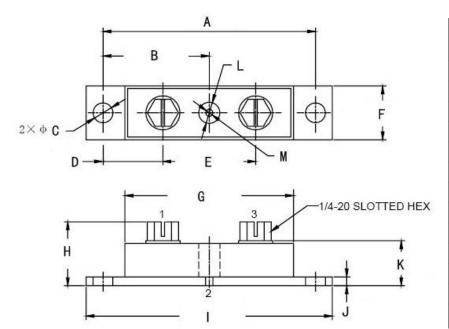






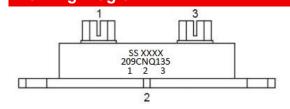


## Mechanical Dimensions PRM4 Non-Isolated(Millimeters/Inches)



SYMBOL	Millimeters		Inches		
STIVIBUL	Min.	Max.	Min.	Max.	
Α	78.74	81.28	3.100	3.200	
В	37.47	42.55	1.475	1.675	
С	6.89	7.69	0.271	0.303	
D	19.51	24.59	0.768	0.968	
E	33.02	38.10	1.300	1.500	
F	17.78	20.32	0.700	0.800	
G	60.96	64.77	2.400	2.550	
Н	17.26	23.25	0.680	0.915	
I	90.17	92.71	3.550	3.650	
J	3.02	3.68	0.119	0.145	
K	14.30	16.15	0.563	0.636	
L	9.27	10.79	0.365	0.425	
М	4.37	5.28	0.172	0.208	

### **Marking Diagram**



#### Where XXXX is YYWW

209CNQ135 = Part name SS = SS YY = Year WW = Week

**Cautions:** Molding resin Epoxy resin UL:94V-0

## **Ordering Information**

Device	Package	Shipping	
209CNQ SERIES	PRM4(Non- Isolated) (Pb-Free)	9 pcs/box	









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